NSN 5961-01-512-9117



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-512-9117 **Inclosure Material:** Plastic **Overall Length:** Between 0.189 inches and 0.220 inches **Overall Height:** Between 0.075 inches and 0.106 inches **Overall Width:** Between 0.089 inches and 0.116 inches **End Application:** 1520-01-355-8250 **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 7.00 amperes forward current, average of standard range **Product Name:** Power schottky rectifier **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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